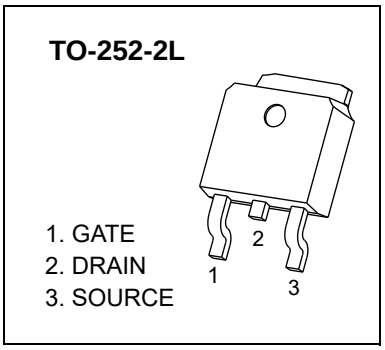
TO-252-2L Plastic-Encapsulate MOSFETS

CJU04N50M1 N-Channel Power MOSFET

$V_{(BR)DSS}$	$R_{DS(on)}$TYP	I_D
500V	1.2Ω@10V	4A



GENERAL DESCRIPTION

The CJU04N50M1 is an N-channel mode power MOSFET using advanced technology to provide costomers with planar stripe. This technology specializes in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode. The CJU04N50M1 is universally applied in high efficiency switch mode power supply.

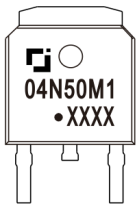
FEATURE

- Excellent package for good heat dissipation
- High switching speed
- 100% avalanche tested

APPLICATION

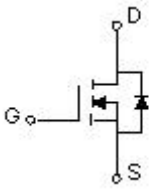
- Power switching application
- DC/DC converters

MARKING



04N50M1= Device code.
Solid dot = Green molding compound device, if none, the normal device
XXXX=Code

EQUIVALENT CIRCUIT



Maximum ratings (T_J=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	500	V
Gate-Source Voltage	V_{GS}	±30	
Continuous Drain Current	I_D ①	4	A
Pulsed Drain Current	I_{DM} ①②	16	
Single Pulsed Avalanche Energy	E_{AS} ③	180	mJ
Power Dissipation	P_D ①	104	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$ ⑥	62.5	℃/W
Thermal Resistance from Junction to Case	$R_{\theta JC}$ ①	1.2	℃/W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 ~+150	℃

MOSFET ELECTRICAL CHARACTERISTICS

T_J=25℃ unless otherwise specified

Parameter	Symbol	Test Condition		Min	Typ	Max	Unit
Off characteristics							
Drain-source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D =250μA		500	-	-	V
Zero gate voltage drain current	I_{DSS}	V_{DS} =500V, V_{GS} =0V	T_J=25℃	-	-	1.0	μA
			T_J=125℃	-	-	100	
Gate-body leakage current	I_{GSS}	V_{DS} =0V, V_{GS} =±30V		-	-	±100	nA
On characteristics④							
Gate-threshold voltage	$V_{GS(th)}$	V_{DS} =V_{GS}, I_D =250μA		2.0	3.0	4.0	V
Static drain-source on-resistance	$R_{DS(on)}$	V_{GS} =10V, I_D =2A		-	1.2	1.5	Ω
Dynamic characteristics ⑤							
Input capacitance	C_{iss}	V_{DS} =50V,V_{GS} =0V,f =1MHz		-	639	-	pF
Output capacitance	C_{oss}			-	41	-	
Reverse transfer capacitance	C_{rss}			-	2	-	
Gate resistance	R_g	f =1MHz		-	3.0	-	Ω
Switching characteristics ⑤							
Total gate charge	Q_g	V_{DS} =400V,V_{GS} =6V,I_D =4A		-	6	-	nC
Total gate charge	Q_g	V_{DS} =400V,V_{GS} =10V,I_D =4A		-	10	-	
Gate-source charge	Q_{gs}			-	3.5	-	
Gate-drain charge	Q_{gd}			-	2.5	-	
Turn-on delay time	$t_{d(on)}$	V_{DD}=250V, V_{GS}=10V, R_G=10Ω, I_D =4A		-	7.2	-	ns
Turn-on rise time	t_r			-	5.5	-	
Turn-off delay time	$t_{d(off)}$			-	13.3	-	
Turn-off fall time	t_f			-	6.2	-	
Drain-Source Diode Characteristics							
Drain-source diode forward voltage	V_{SD}④	V_{GS} =0V,I_S =7A		-	-	1.2	V
Maximum continuous drain-source diode forward current	I_S①			-	-	4	A
Maximum pulsed drain-source diode forward current	I_{SM}①②			-	-	16	A
Reverse recovery time	trr	dIF/dt = 100A/μs, I_S = 10A, V_{DD} = 50V		-	293	-	ns
Reverse recovery charge	Qrr			-	2375	-	nC

Notes :

1.T_C=25℃ Limited only by maximum temperature allowed.

2.P_W≤10μs, Duty cycle≤1%.

3.EAS condition: V_{DD}=50V,V_{GS}=10V, L=10mH, R_g=25Ω Starting T_J = 25℃.

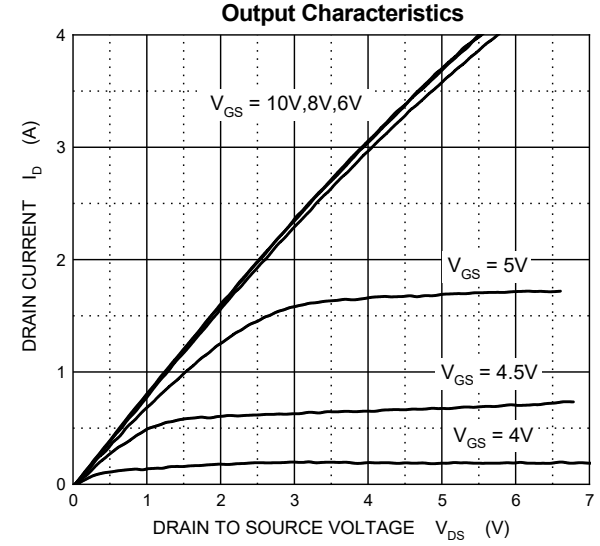
4.Pulse Test : Pulse Width≤300μs, duty cycle ≤2%.

5.Guaranteed by design, not subject to production.

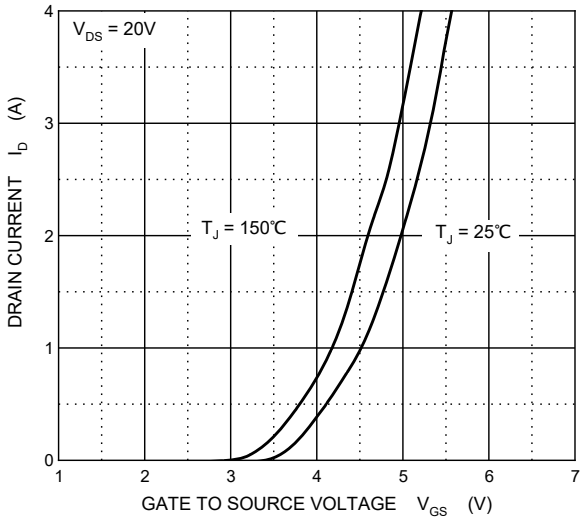
6.Device mounted on 1 in^2 FR-4 board with 2oz. single-sided Copper, in a still air environment with T_A=25℃.

Typical Characteristics (T_J = 25℃, unless otherwise specified)

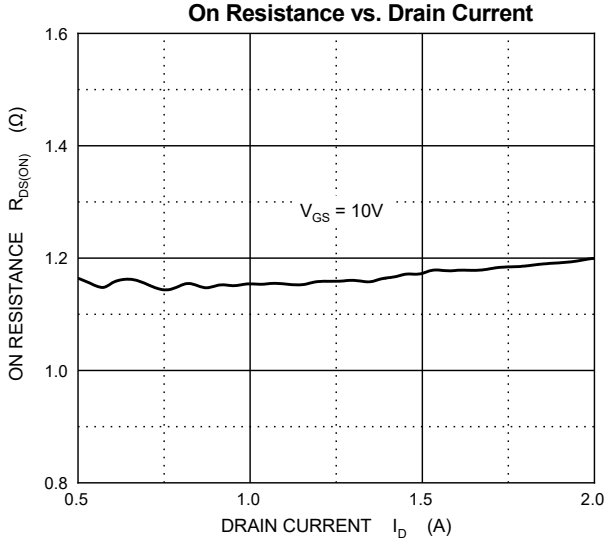
Output Characteristics



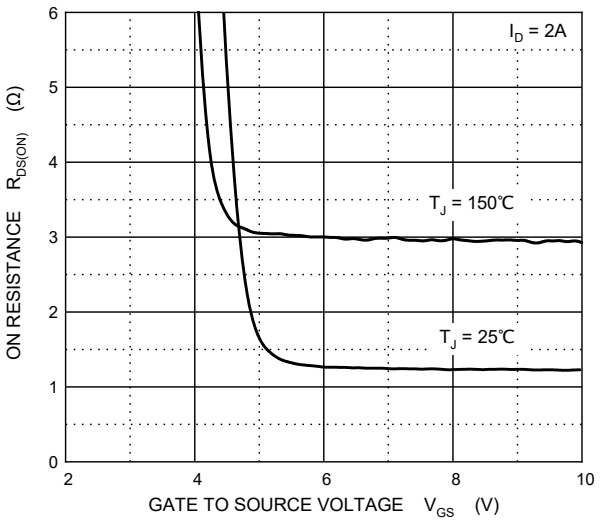
Transfer Characteristics



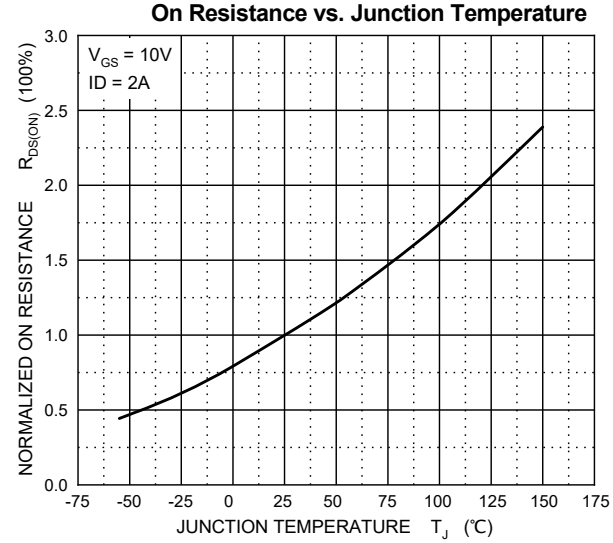
On Resistance vs. Drain Current



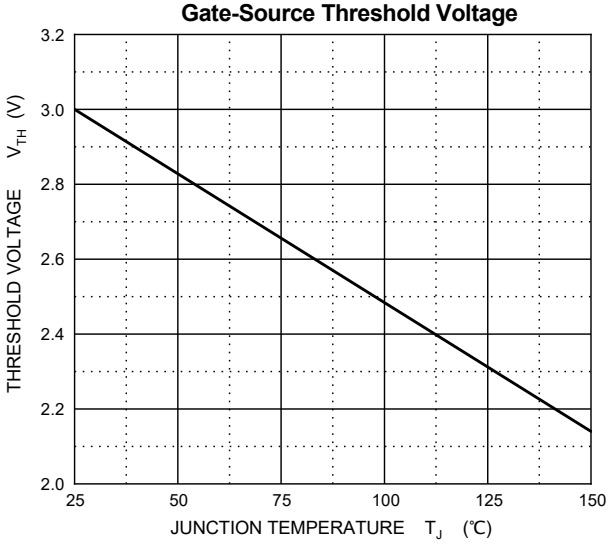
On Resistance vs. Gate-Source Bias



On Resistance vs. Junction Temperature



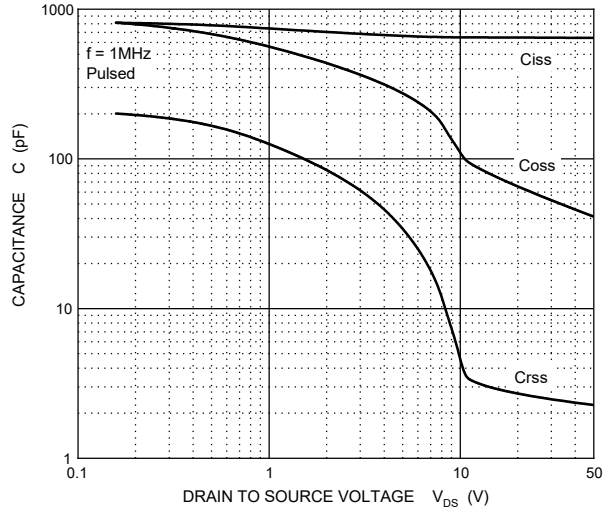
Gate-Source Threshold Voltage



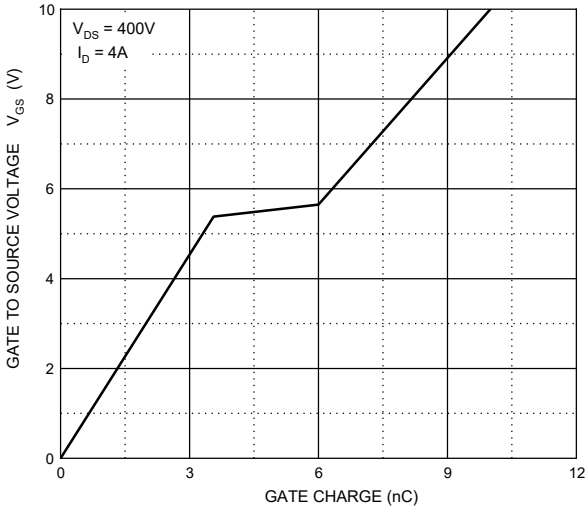
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Typical Characteristics (T_J = 25℃, unless otherwise specified)

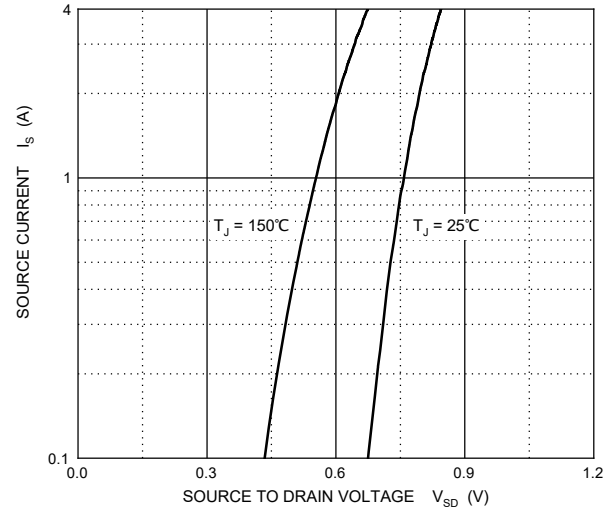
Typical Capacitances



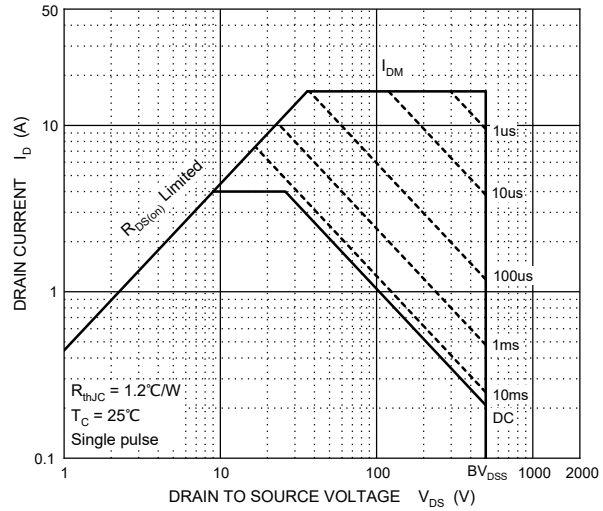
Gate Charge



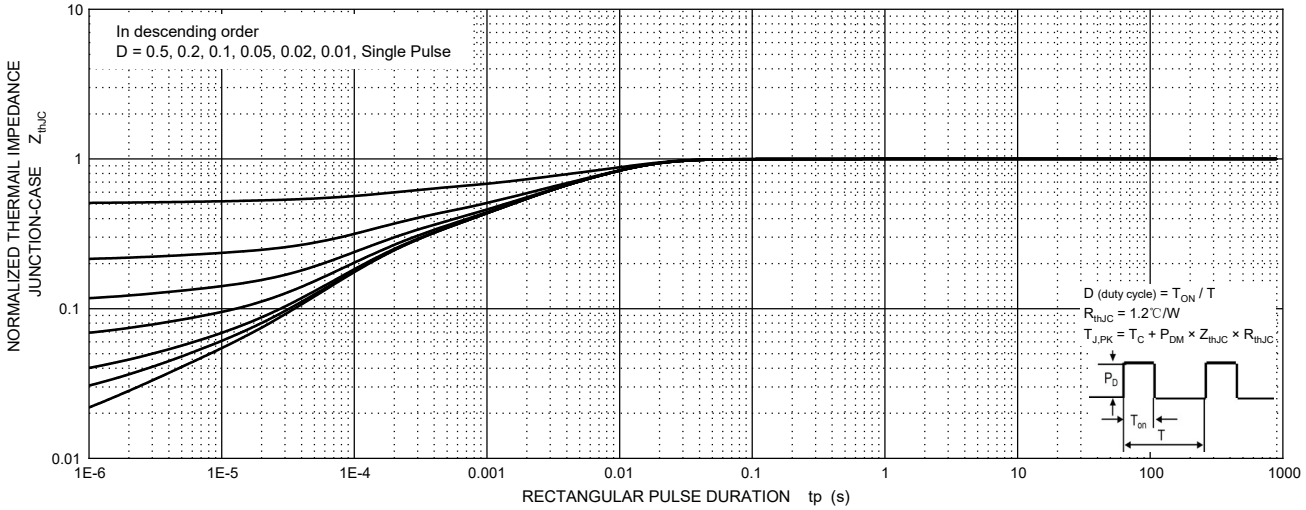
Source-Drain Diode Forward Characteristics



Maximum Safe Operating Area

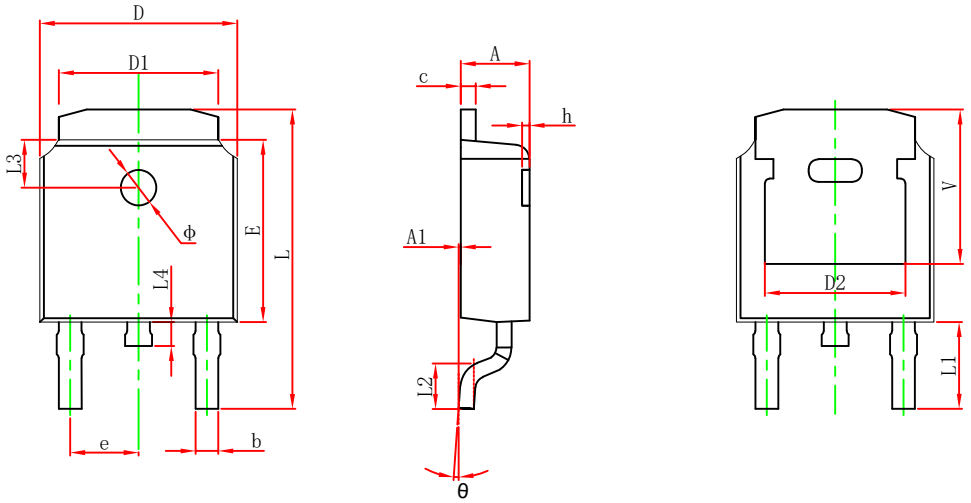


Transient Thermal Impedance, Junction-Case



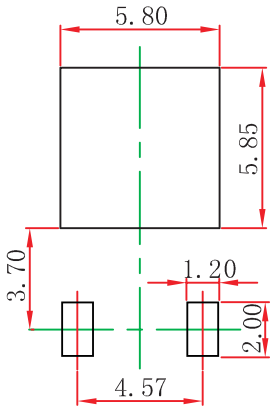
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TO-252-2L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.635	0.770	0.025	0.030
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.712	10.312	0.382	0.406
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.250 REF.		0.207 REF.	

TO-252-2L Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.

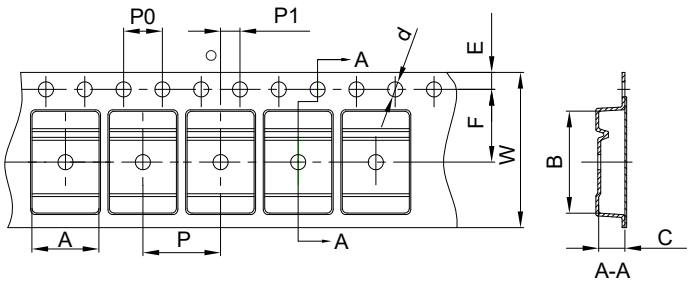
NOTICE

SZCJ reserves the right to make modifications,enhan nts,improvements,corrections or other es without further notice to any product herein. SZCJ does not assume any liability arising out of the application or use of any product described h

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TO-252-2L Tape and Reel

TO-252-2L Embossed Carrier Tabe

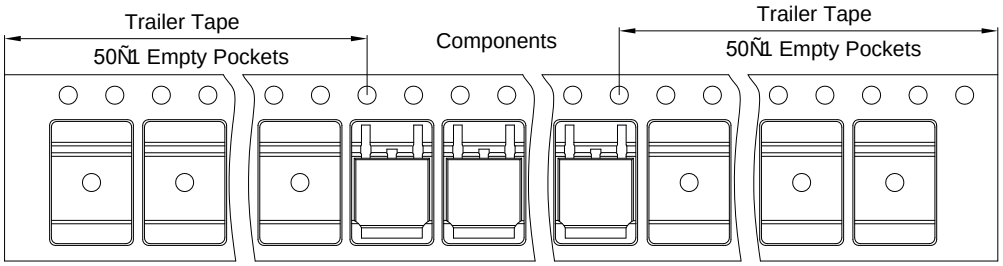


Packaging Description:

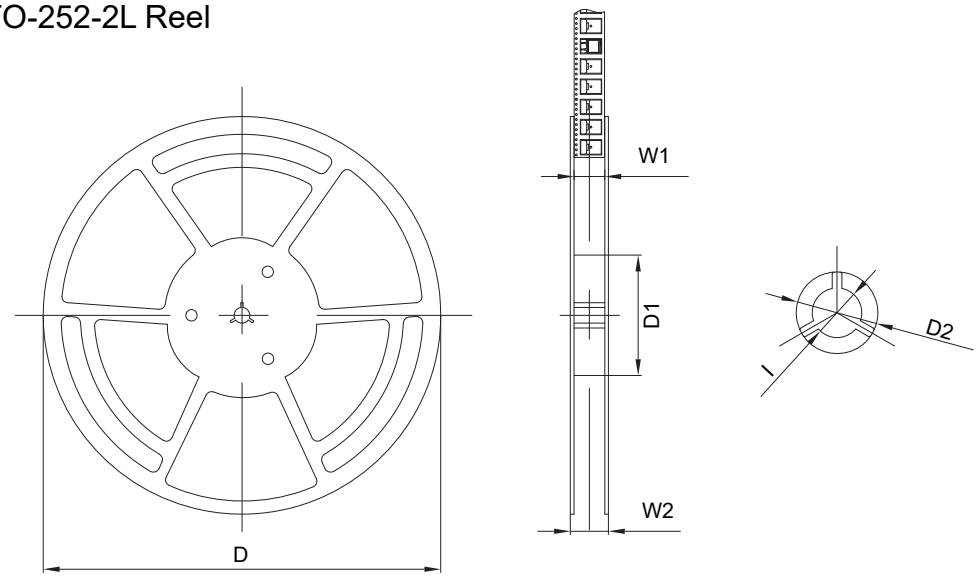
TO-252-2L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Hear Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 2500 units per 13″ or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
TO-252	6.90	10.50	2.70	Φ1.55	1.75	7.50	4.00	8.00	2.00	16.00

TO-252-2L Tape Leader and Trailer



TO-252-2L Reel



Dimensions are in millimeter						
Reel	D	D1	D2	W1	W2	I
13" Dia	330.00	100.00	Φ21.00	16.40	21.40	Φ13.00

Reel	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)
2500 pcs	13 inch	5000 pcs	360×360×65	25000 pcs	378×358×382